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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>				Application Number	Filed Herewith
				Filing Date	March 11, 2004
				First Named Inventor:	JengPing Lu
				Examiner name: unknown	GROUP: unknown
Sheet	1	of	1	Attorney Docket Number	A3490 (XCP-040)

U.S. PATENT DOCUMENTS

Examiner Initials*	Cited No. ¹	Document Number Number - Kind Code ^{2(f known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Passages or Figures Appear
	A01	US-3,842,189	10/15/1974	Southgate	
	A02	US-5,613,861	03/25/1997	Smith et al.	
		US-			
		US-			
		US-			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document Cntry Code ³ Number ⁴ Kind Code ^{5 (f known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Passages or Figures Appear	T ⁶

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Fonash: "Integration Of Thin Film Electronics And MEMs", SPIE Vol. 2722, 2/96, pp. 66-74.
	Martin et al.: "High-Voltage Amorphous Silicon Thin-Film Transistors", IEEE Transactions On Electron Devices, Vol. 40, No. 3, March 1993, pp. 634-643.
	Huang et al.: "Device Sensitivity Of Field-Plated Polysilicon High-Voltage TFT's And Their Application To Low-Voltage Operation", IEEE Electron Device Letters, Vol. 11, November 1990, pp. 541-543.
	Welsh et al.: "NCAP Displays: Optical Switching And Dielectric Properties", SID 90 Digest, 1990, pp. 220-223.
	Chuang et al.: "Page-Wide High-Voltage Polysilicon TFT Array For Electronic Printing", SID 90 Digest, 1990, pp. 508-511.

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